# **ELECTRONICS DEVICES AND CIRCUITS**

6

### OBJECTIVE

# DRIFT VELOCITY, COLLISION TIME, MEAN FREE PATH AND MOBILITY,

# DRIFT VELOCITY

- The drift velocity is the average <u>velocity</u> that a particle, such as an <u>electron</u>, attains due to an <u>electric field</u>. It can also be referred to as axial drift velocity since particles defined are assumed to be moving along a plane. In general, an electron will 'rattle around' in a <u>conductor</u> at the <u>Fermi velocity</u> randomly. An applied electric field will give this random motion a small net velocity in one direction.
- In a <u>semiconductor</u>, the two main carrier scattering mechanisms are <u>ionized impurity scattering</u> and <u>lattice</u> <u>scattering</u>.

# DRIFT VELOCITY

Because current is proportional to drift velocity, which is, in turn, proportional to the magnitude of an external electric field, <u>Ohm's law</u>can be explained in terms of drift velocity.

#### Microscopic understanding of mobility?

How long does a carrier move in time before collision ?

The average time taken between collisions is called as relaxation time,  $\mathcal{T}($ or mean free time)

How far does a carrier move in space (distance) before a collision?

The average distance taken between collisions is called as mean free path, Z.

#### Calculation

#### Drift velocity=Acceleration x Mean free time

$$V_d = \frac{F}{m^*} \times \tau$$

Force is due to the applied field, F=qE

$$V_{d} = \frac{F}{m^{*}} \times \tau = \frac{qE}{m^{*}}\tau$$

$$V_d = \mu E \Longrightarrow \mu = \frac{q\tau}{m^*}$$

#### Calculation

 Calculate the mean free time and mean free path for electrons in a piece of n-type silicon and for holes in a piece of p-type silicon.

$$\tau = ? \qquad l = ? \qquad m_e^* = 1.18 \ m_o \qquad m_h^* = 0.59 m_o$$
$$\mu_e = 0.15 \ m^2 / (V - s) \qquad \mu_h = 0.0458 \ m^2 / (V - s)$$
$$\tau_e = \frac{\mu_e m_e^*}{q} = 10^{-12} \sec \qquad \tau_h = \frac{\mu_h m_h^*}{q} = 1.54 \times 10^{-13} \sec$$
$$v_{th_{elec}} = 1.08 \times 10^5 \ m / s \qquad v_{th_{hole}} = 1.052 \times 10^5 \ m / s$$

$$l_e = v_{th_{elec}} \tau_e = (1.08x10^5 \, m/s)(10^{-12} \, s) = 10^{-7} \, m$$
$$l_h = v_{th_{hole}} \tau_h = (1.052x10^5 \, m/s)(1.54x10^{-13} \, \text{sec}) = 2.34x10^{-8} \, m$$